

Phase Formation in the SnO₂-ZnO binary System

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The present work deals with phase formation studies in the SnO₂-ZnO binary system over the concentration range in the 600-1500°C temperature domain.

ABSTRACT

The Sn-Zn-O ceramics are very interesting materials for the applications as varistors, electrodes, catalysts and gas sensors.

The present work deals with phase formations studies in the SnO₂-ZnO binary system over the whole concentration range.

High-temperature interactions of the samples thermally treated in the 1000-1500°C domain were evaluated by XRD and FT-IR Spectroscopy.

Morphological characteristics were determined from linear shrinkage, porosity and density measurements and Scanning electron microscopy

Besides SnO2 and ZnO only Zn2SnO4 ternary compound was found in our experimental conditions

A correlation of the observed fluorescence emission in the Sn-Zn-O samples with structural changes resulting from interactions during the thermal treatments was established.

EXPERIMENTAL

Preparation of the samples

Starting materials

•SnO₂ (Merck) - p.a reagent grade

•ZnO (Fluka) - p.a reagent grade

The SnO_2 and ZnO with grain size belong 60 μm and composition presented in Table 1 were wet homogenized in the agate mortar absolute ethanol.

Cylindrical samples with Φ=10 mm and h=2-3 mm were obtained by pressing at 100 MPa.

Thermal treatment:

•Non-isothermal conditions up to 1500°C (heating rate 5ºC/minute).

•Isothermal conditions at 600°C - 1500°C; 2 or 10 hours plateau

Methods of characterization

Structural Characterization:

• XRD analysis was performed with a DRON UM1 diffractometer.

2θ equipped with a graphite monochromatized using Co Kα radiation $(\lambda = 1.79021 \text{ Å}).$

- FT-IR spectroscopy was made with a Nicolet 6700 apparatus in 400-1400 cm⁻¹ domain.
- The fluorescence spectra (emission) were recorded with Perkin Elmer 204 spectrofluorimeter (having a Xe lamp of 150 W), interfaced to a computer, permitting a prestabilized reading time of the data. Usually the time range between two measurements is 550

Morphological characterization:

- · Linear shrinkage
- · Apparent porosity in methanol
- Arhimedic density
- · Scanning electron microscopy

Structural characterization

RESULTS

Table 1 Initial and phase composition of the studied samples Sample Initial Composition Phase composition ZnO 600 °C 1000 ° C 1300 °C 1SZO 100 SnO₂ SnO₂ SnO₂ SnO₂ SnO₂,Zn₂SnO₄ SnO₂,ZnO SnO₂, Zn₂SnO₄ZnO 3SZO 95 SnO₂,ZnO SnO₂, Zn₂SnO₄,ZnO SnO₂,Zn₂SnO₄ SnO₂,Zn₂SnO 4SZO 90 10 SnO₂, ZnO SnO₂, Zn₂SnO₃, ZnO SnO₂,Zn₂SnO₂ SnO₂,Zn₂SnO 5SZO 80 20 SnO₃,ZnO SnO₃, Zn₃SnO₄,ZnO SnO₃,Zn₃SnO₄ SnO₃,Zn₃SnO₄ SnO₂,ZnO SnO₂, Zn₂SnO₄, ZnO SnO₂,Zn₂SnO₄ SnO₂,Zn₂SnO₄ SnO2,ZnO SnO₂, Zn₂SnO₄,ZnO 8SZO SnO.,ZnO SnO₂,Zn₂SnO₄ SnO₂,Zn₂SnO₄ SnO₂,Zn₂SnO 9SZO 60 SnO₂,ZnO SnO₂,Zn₂SnO₄ SnO₂,Zn₂SnO₄ SnO₂,Zn₂SnO₄ SnO₂,ZnO Zn₂SnO₄, SnO₂, ZnO 11SZO 30 70 SnO₂,ZnO Zn₂SnO₄, ZnO, SnO₂, Zn₂SnO₄, ZnO Zn₂SnO₄, ZnO Zn,SnO, ZnO Zn,SnO, ZnO 12SZO 20 80 SnO₂,ZnO Zn₂SnO₄ ZnO, SnO₂, 13SZO SnO₂,ZnO Zn₂SnO₄ ZnO₅SnO₂ Zn,SnO₄ ZnO Zn,SnO₄ ZnO 14SZO SnO₂, ZnO Zn₂SnO₄, ZnO, SnO₂, Zn₂SnO₄, ZnO Zn₂SnO₄, ZnO 15SZO 97.5 SnO₂,ZnO Zn₂SnO₄, ZnO, SnO₂, Zn₂SnO₄, ZnO Zn₂SnO₄, ZnO

ASTM Files: SnO₂: 5-467; ZnO: 5-664; Zn₂SnO₄: 24-147

At 1000 °C the following reaction take place:

SnO₂ +2ZnO →Zn₂SnO₄

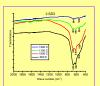
The presence of the Zn₂SnO₄ compound even if for 2 SZO sample (2.5% mol ZnO) was observed by X-ray diffraction analysis.

At temperatures ≥1000°C for the 10SZO sample

only Zn, SnO4 phase was identified.

FT-IR Spectroscopy

100



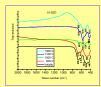
16SZO

FT-IR Spectroscopy of the 2SZO at different temperatures



ZnO

ZnO

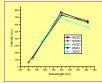


For the sample 2SZO at 1300°C IR flattening of IR characteristics bands can be seen. That is due to the solid

can be seen. That is due to the solid solutions formation of SnO_{2.s}.

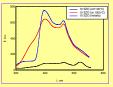
For the sample 8SZO and 10SZO at 1000°C the appearance of the new IR band at 572 cm⁻¹ can be observed. This band could be assigned to the SnO-Zn bonding of the Zn₂SnO₄ inverse

Fluorescence Spectroscopy



The fluorescence emission maxima, $\lambda_{\rm em}$, and relative fluorescence intensities, $I_{\rm f}$ of the initial Sn-Zn oxide mixtures.





The fluorescence emission maxima, $\lambda_{\rm em}$ and relative fluorescence intensities, $I_{\rm r}$ of the samples thermally treated at different temperature. He fluorescence intensities, $\lambda_{\rm em} = 1000$ the temperature, $\lambda_{\rm em} = 100$ m different temperatures; $\lambda_{\rm em} = 270$ nm

Initial mixtures of Sn-Zn oxides present

similar relative fluorescence intensities.

In the case of the samples thermally treated at 1000°C smaller relative treated at 1000°C smaller relative fluorescence intensities are observed for the samples 15SZO and 16SZO(with highest ZnO content).

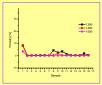
For the samples thermally treated at 1100°C the fluorescence emission quenched due to the formation of the Zn₂SnO₄ compound reachable.

compound probably

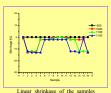
Morphological characterization



Apparent porosity of the sa thermally treated at di temperatures, 10 h plateau.



thermally treated at dit temperatures, 90 min. plateau.

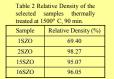


thermally treated at different temperatures, 10 h plateau



thermally treated at diff temperatures, 90 min. plateau





SEM image of the 2SZO sample



phase was visualized by SEM. Probably the densification occurs by the formation of oxygen vacancies according to the following reaction: $ZnO \rightarrow Zn_{Sn} + V_{\bar{0}} + O_{\bar{0}}^{x}$ $V_0^x \rightarrow V_0 + e^x$

CONCLUSIONS

- Phase formation in the SnO₂-ZnO binary system in the whole concentration range on the 600-1500°C temperature domain was studied.
 •At 1000 °C the Zn₂SnO₄ compound with inverse spinel structure was formed. The change coordination of the Zn ions due to the formation of the inverse spinel was
- Solid solutions with rutile structure was formed at 1300 °C in the riche SnO₂ domain
- •Dense ceramics with relative density higher then 95% were obtained in both riche SnO₂ and ZnO domains.
 •All the mechanical mixtures belonging to the SnO₂-ZnO system excepting pure SnO₂ present fluorescence emission in UV range as well as the ceramics obtained after thermal treatment at 1000 °C. The change coordination of Zn ions through formation of Zn₂SnO₄ inverse spinel quenched fluorescence emission.

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